BY251G – BY254G

Taiwan Semiconductor

3A, 200V - 800V Standard Rectifier

FEATURES

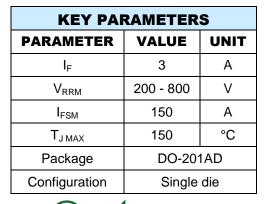
- High efficiency, Low $V_{\rm F}$
- High current capability
- High reliability
- High surge current capability
- Low power loss
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

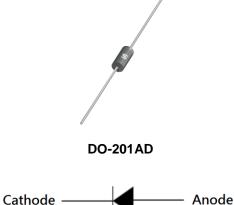
- DC to DC converter
- Switching mode converters and inverters
- General purpose

MECHANICAL DATA

- Case: DO-201AD
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 1.20g (approximately)







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	BY251G	BY252G	BY253G	BY254G	UNIT
Marking code on the device		BY251G	BY252G	BY253G	BY254G	
Repetitive peak reverse voltage	V _{RRM}	200	400	600	800	V
Reverse voltage, total rms value	V _{R(RMS)}	140	280	420	560	V
Forward current	I _F	3			Α	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	150			А	
Junction temperature	TJ	-55 to +150			°C	
Storage temperature	T _{STG}	-55 to +150			°C	





THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-ambient thermal resistance	R _{eja}	40	°C/W	

ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	$I_F = 3A, T_J = 25^{\circ}C$	V _F	-	1.0	V
Reverse current @ rated V _R ⁽²⁾	$T_J = 25^{\circ}C$	1	-	5	μA
Reverse current @ fated v _R **	$T_J = 125^{\circ}C$	- I _R	-	100	μA
Junction capacitance	$1MHz, V_R = 4.0V$	CJ	40	-	pF

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING		
BY25xG	DO-201AD	1,250 / Tape & Reel		
BY25xG A0G	DO-201AD	500 / Ammo box		

Notes:

1. "x" defines voltage from 200V (BY251G) to 800V (BY254G)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

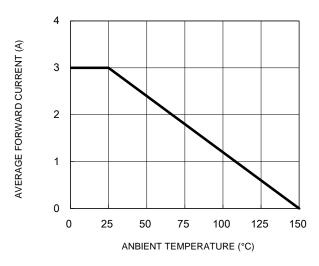


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

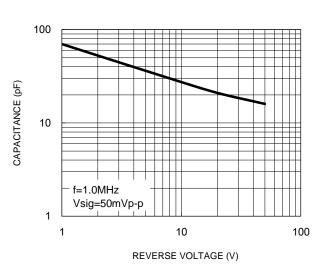
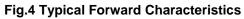
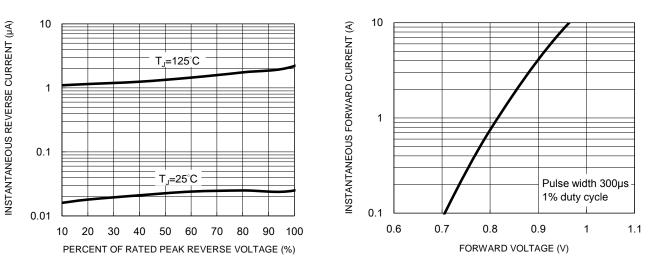


Fig.2 Typical Junction Capacitance





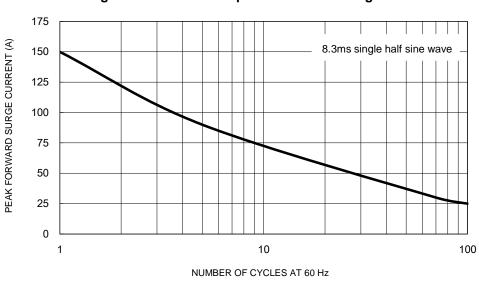
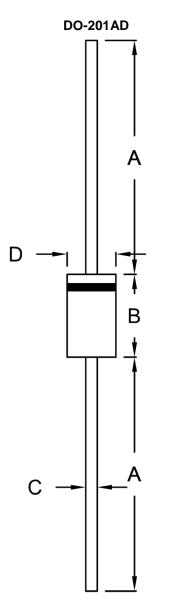


Fig.5 Maximum Non-Repetitive Forward Surge Current





PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
Divi.	Min.	Max.	Min.	Max.	
А	25.40	-	1.000	-	
В	8.50	9.50	0.335	0.374	
С	1.20	1.30	0.047	0.051	
D	5.00	5.60	0.197	0.220	

MARKING DIAGRAM



= Marking Code
= Green Compound
= Date Code
= Factory Code



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